

IPN60R2K1CEATMA1

IPN60R2K1CEATMA1 Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IPN60R2K1CEATMA1 Specifications

Manufacturer Part Number	IPN60R2K1CEATMA1
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	SOT-223-3
Series	CoolMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	3.7A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	3.5V @ 60µA
Gate Charge (Qg) (Max) @ Vgs	6.7nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	140pF @ 100V
Vgs (Max)	$\pm 20\mathrm{V}$
FET Feature	Super Junction
Power Dissipation (Max)	5W (Tc)
Rds On (Max) @ Id, Vgs	2.1 Ohm @ 800mA, 10V
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-SOT223
Package / Case	SOT-223-3
	Report errors?

IPN60R2K1CEATMA1 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

DISCOVER

IPN60R2K1CEATMA1 Payment Methods





IPN60R2K1CEATMA1 Shipping Methods



If you have any question about IPN60R2K1CEATMA1, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com